2SC5957



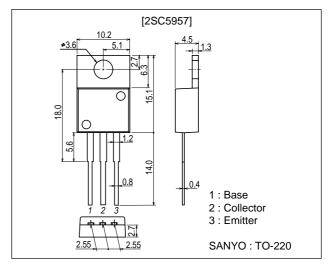
Switching Regulator Applications

Features

- · High breakdown voltage and high reliability.
- · High-speed switching.
- · Wide ASO.
- · Adoption of MBIT process.

Package Dimensions

unit : mm 2010C



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		500	V
Collector-to-Emitter Voltage	VCEO		400	V
Emitter-to-Base Voltage	VEBO		7	V
Collector Current	IC		10	Α
Collector Current (Pulse)	ICP	PW≤300μs, duty cycle≤10%	20	Α
Base Current	IΒ		3.5	Α
Collector Dissipation	De		1.75	W
Collector Dissipation	PC	Tc=25°C	50	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter Syn	Symbol	Conditions	Ratings			Unit
	Symbol	Conditions	min	typ	max	Offic
Collector Cutoff Current	ІСВО	V _{CB} =400V, I _E =0			10	μΑ
Emitter Cutoff Current	IEBO	VEB=5V, IC=0			10	μΑ

Continued on next page.

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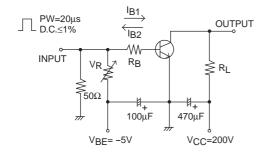
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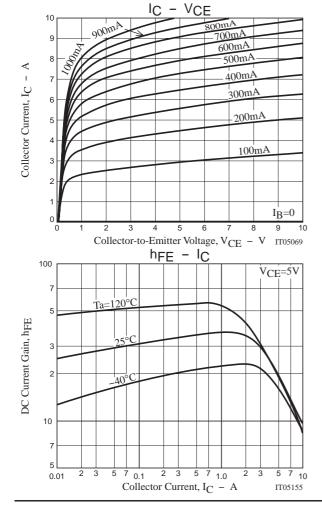
Parameter	Symbol Conditions	Conditions	Ratings			Unit
		min	typ	max	Onit	
	hFE1	V _{CE} =5V, I _C =1.2A	20*		50*	
DC Current Gain	hFE2	V _{CE} =5V, I _C =6A	10			
	hFE3	VCE=5V, IC=1mA	10			
Gain-Bandwidth Product	fT	V _{CE} =10V, I _C =1.2A		15		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		80		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	IC=6A, IB=1.2A			0.8	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =6A, I _B =1.2A			1.5	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =1mA, I _E =0	500			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=5mA, RBE=∞	400			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=1mA, IC=0	7			V
Turn-ON Time	ton	I _C =7A, I _{B1} =1.4A, I _{B2} =-2.8A, R _L =28.6Ω, V _{CC} =200V			0.5	μs
Storage Time	t _{stg}	I _C =7A, I _{B1} =1.4A, I _{B2} =-2.8A, R _L =28.6Ω, V _{CC} =200V			2.5	μs
Fall Time	tf	I _C =7A, I _{B1} =1.4A, I _{B2} =-2.8A, R _L =28.6Ω, V _{CC} =200V			0.3	μs

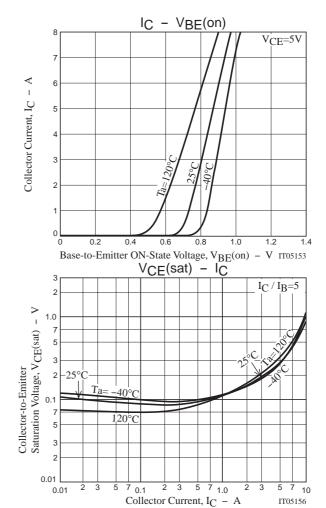
*: The hFE1 of the 2SC5957 is classified as follows.

Rank	М	N		
hFE	20 to 40	30 to 50		

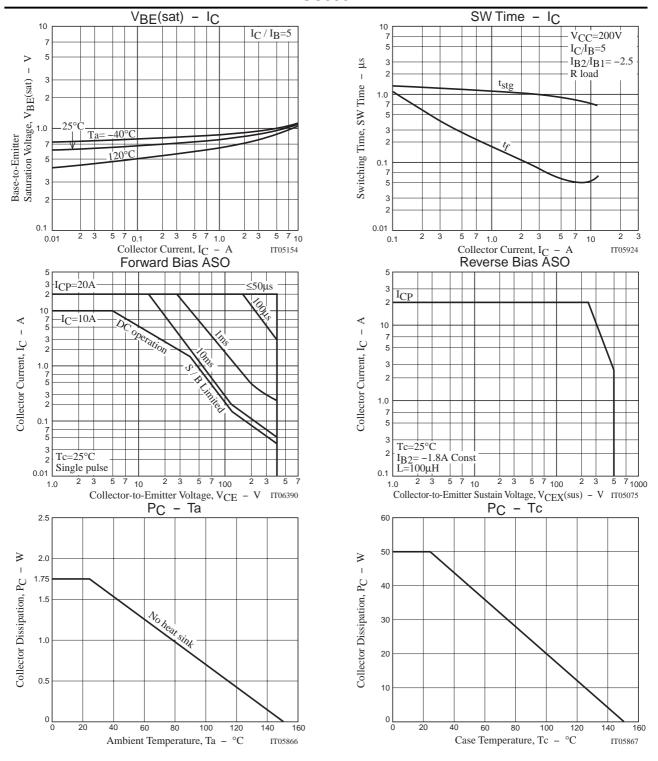
Switching Time Test Circuit







2SC5957



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